onsemi

MOSFET - Power, Single N-Channel

40 V, 4.5 mΩ, 80 A

NVMFS5C456N

Features

- Small Footprint (5x6 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- NVMFS5C456NWF Wettable Flank Option for Enhanced Optical Inspection
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	40	V
Gate-to-Source Voltage			V _{GS}	±20	V
Continuous Drain	Steady	T _C = 25°C	I _D	80	А
Current R _{θJC} (Notes 1, 3)		$T_{C} = 100^{\circ}C$		56	
Power Dissipation	State	T _C = 25°C	PD	55	W
R _{θJC} (Note 1)		T _C = 100°C		27	
Continuous Drain		$T_A = 25^{\circ}C$	I _D	20	А
Current R _{θJA} (Notes 1, 2, 3)	Steady State	T _A = 100°C		14	
Power Dissipation		T _A = 25°C	PD	3.6	W
$R_{\theta JA}$ (Notes 1 & 2)		T _A = 100°C		1.8	
Pulsed Drain Current	T _A = 25	°C, t _p = 10 μs	I _{DM}	400	А
Operating Junction and Storage Temperature Range			T _J , T _{stg}	–55 to +175	°C
Source Current (Body Diode)			ا _S	45.5	А
Single Pulse Drain-to-Source Avalanche Energy (I _{L(pk)} = 5.22 A)			E _{AS}	239	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

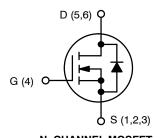
Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State	$R_{\theta JC}$	2.7	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	42	

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

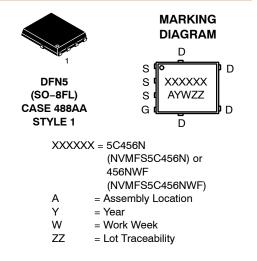
2. Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.

Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.

V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX		
40 V	4.5 m Ω @ 10 V	80 A		



N-CHANNEL MOSFET



ORDERING INFORMATION

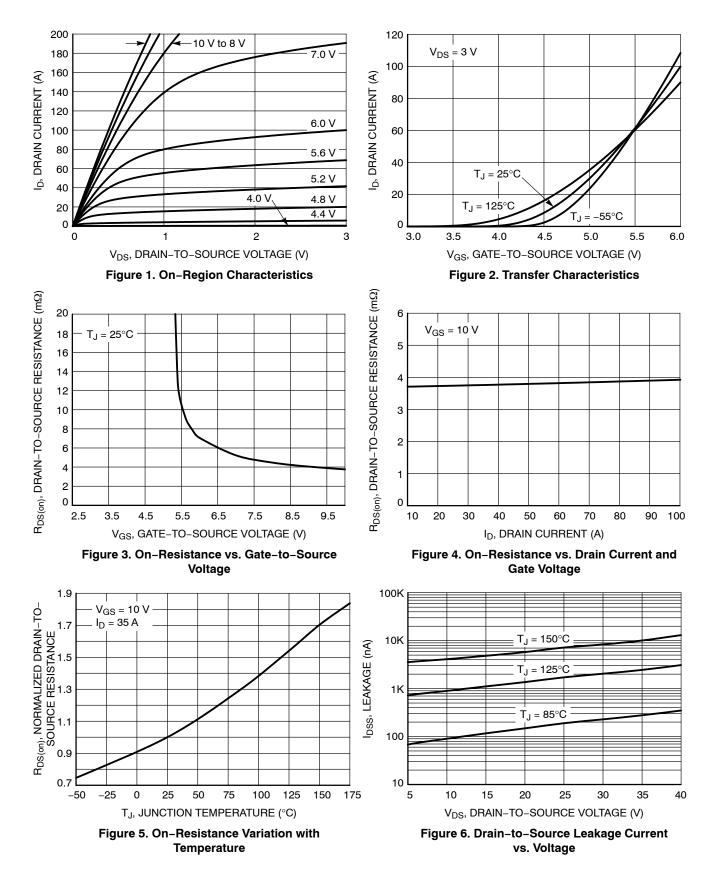
See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise specified)

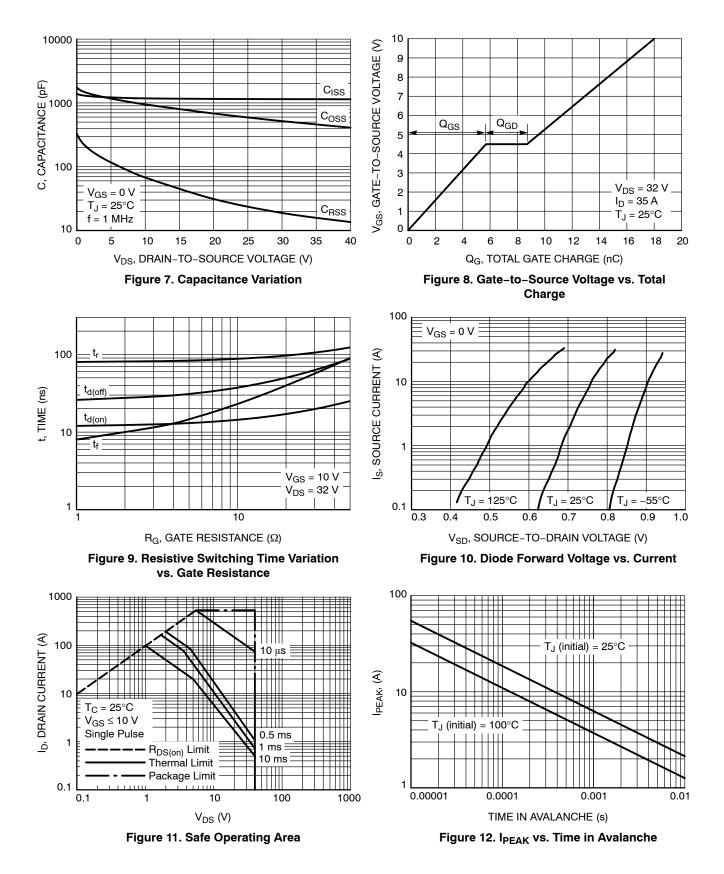
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I _D = 250 μ A		40			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} / T _J				23		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V,$ $T_{J} = 25 °$				10	
		V _{DS} = 40 V	T _J = 125°C			250	μΑ
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 V, V_{GS} = 20 V$				100	nA
ON CHARACTERISTICS (Note 4)							
Gate Threshold Voltage	V _{GS(TH)}	V_{GS} = V_{DS} , I_D = 250 μ A		2.5		3.5	V
Threshold Temperature Coefficient	V _{GS(TH)} /T _J				-6.5		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 35 A		3.8	4.5	mΩ
Forward Transconductance	9 _{FS}	V _{DS} =15 V, I _D = 35 A			57		S
CHARGES, CAPACITANCES & GATE RE	SISTANCE			-			
Input Capacitance	C _{ISS}	V _{GS} = 0 V, f = 1 MHz, V _{DS} = 25 V			1150		pF
Output Capacitance	C _{OSS}				600		
Reverse Transfer Capacitance	C _{RSS}				25		
Total Gate Charge	Q _{G(TOT)}				18		1
Threshold Gate Charge	Q _{G(TH)}	V_{GS} = 10 V, V_{DS} = 32 V; I _D = 35 A			3.7		nC
Gate-to-Source Charge	Q _{GS}				5.7		
Gate-to-Drain Charge	Q _{GD}				3.0		
Plateau Voltage	V _{GP}				4.5		V
SWITCHING CHARACTERISTICS (Note 5	5)						
Turn-On Delay Time	t _{d(ON)}				12		
Rise Time	tr	V_{GS} = 10 V, V_{DS} = 32 V, I_{D} = 35 A, R_{G} = 1 Ω			80		ns
Turn-Off Delay Time	t _{d(OFF)}				26		
Fall Time	t _f				8		
DRAIN-SOURCE DIODE CHARACTERIS	TICS						
Forward Diode Voltage V _{SD}	V _{SD}	V _{GS} = 0 V,	$T_J = 25^{\circ}C$		0.82	1.2	
	I _S = 35 A	T _J = 125°C		0.69		V	
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, dI _S /dt = 100 A/µs, I _S = 35 A			33		1
Charge Time	t _a				16		ns
Discharge Time	t _b				17		1
Reverse Recovery Charge	Q _{RR}				18		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse Test: pulse width $\leq 300 \ \mu$ s, duty cycle $\leq 2\%$. 5. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



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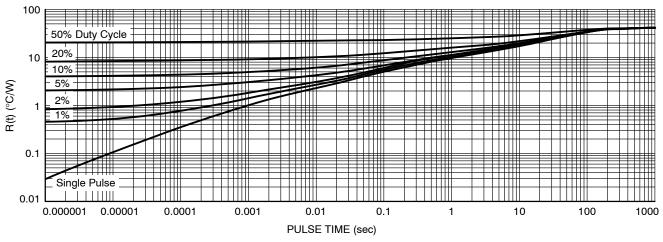


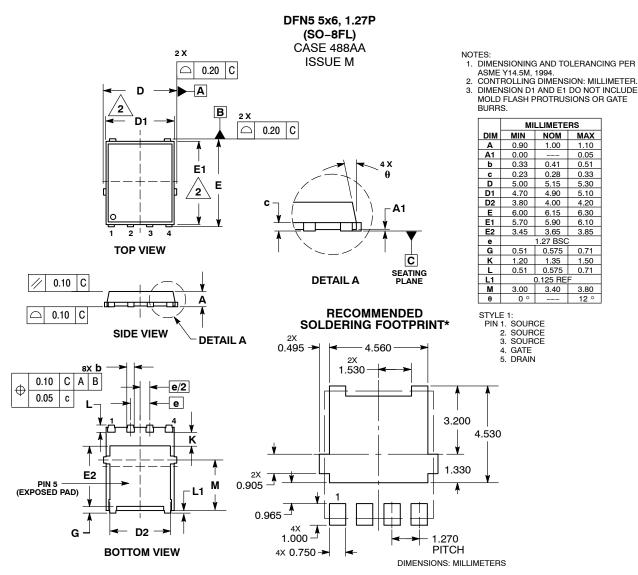
Figure 13. Thermal Characteristics

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NVMFS5C456NT1G	5C456N	DFN5 (Pb–Free)	1500 / Tape & Reel
NVMFS5C456NWFT1G	456NWF	DFN5 (Pb-Free, Wettable Flanks)	1500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS



*For additional information on our Pb–Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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